	Specification		Symbo		Condition / Comment					HTS 240-1200 SCR Unit		
	Maximum Operating Voltage		$V_{O(max)}$		l _{off} < 50 μADC, T _{case} = 70°C					24	kVDC	
SO	Maximum Isolation Vo	VI				GND, continuo	ously		± 50	kVDC		
	Max. Housing Insulation Voltage V _{INS}			Between			face, 3 minutes	3		± 25	kVDC	
	Maximum Turn-On Pe	I _{P(max)}	T _{case} = t _p < 200 µs, duty cycle <1%						12000			
7//			25°C t _p < 1 ms, duty cycle <						6000	ADC		
BSOLUTE M.			t _p < 10 ms, duty cycle <1% t _p < 100 ms, duty cycle <1%						4080 2400			
	Mary Nam Daniellina Da	-								ADC		
	Max. Non-Repetitive Peak Current		I _{p(nr)}	T _{case} = Half sine single pulse, 25°C Half sine single pulse.					24000 48000	ADC		
	Max. Coutinuous Load Current IL			3 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7						3.26	ADC	
				T _{case} = 25°C						0.20	7.00	
	Max. Rate-of-Rise of OFF-State Voltage dv			@ V _{O(max)} , exponential waveform						150	kV/ μ	
	Mary Cartherine Davis	D	T _{cisse} = 25°C Standard devices & FC, forced air 4 m/s						78	10/-44		
	Max. Continuous Powe Linear Derating	P _{d(max)}	Above 25°C			C, forced air 4			1.8	Watt W/K		
	Operating Temperature Range		To				*			-4075	C°	
	Storage Temperature Range		Ts	Standard devices & options CF, GCF, ILC. (Option DLC) Switches with option ILC may require frost protection!						-4075 -5090	C°	
	Max. Permissible Magnetic Field		В	Homogeneous steady-field, surrounding the whole switch						25	mT	
	Max. Auxilliary Voltage		V _{aux}	Built-in overvoltage limiter (replaceable)						5	VDC	
	Permissible Operating Voltage Range		Vo							0 ± 24	kVDC	
	Typical Breakdown Voltage		V _{br}	NOTE: V _{br} is a test parameter for quality control purposes only. Not applicable in				_f > 0.5 mA		>26	kVDC	
SO	Typical Off-State Current		l _{off}	0.8xVo, T _{case} =2570°C, reduced l _{off} on request						< 400	μADC	
	Typical Holding Current		ТОП	0.0400, 1	Tcase=70°C			οι 		35	mADC	
	Typical On-State Voltage		V _{sat}	Fach swit	tching path		0.01 x I _{P(max)}			25	IIIADO	
	Typical off State Voltage		v adi				0.1 x I _{P(max)}			46		
					, ,		1.0 x I _{P(max)}			125	VDC	
	Typical Propagation Delay Time		t _{d(on)}	Resistive load, 0.1 x I _{P(max)} , 0.8 x V _{O(max)} , 50-50%						0.4	μs	
	Typical Output Pulse Jitter		tj				$V_{ctrl} = 5.00 VD$			1	ns	
	Typical Turn-On Rise	t _{r(on)}	Resistive	Resistive load, 10-90% $0.1 \times V_{O(max)}$, $I_L = 0.1 \times I_{p(max)}$					550			
STI								$_{x)}$, $I_{L} = 0.1 \times I_{p(max)}$		170		
RI	T : IT 0"T	ļ.,					$I_{L} = 1.0 \text{ x } I_{p(max)}$		500	ns		
;TE	Typical Turn-Off Time	$t_{\text{off,}}t_{q}$	Resistive	Resistive load, 10-90% $0.1 \times V_{O(max)}, I_L = 0.1 \times I_{p(max)}$				tbd.	ns			
CHARACTERISTICS	On Time	+	$0.8 \times V_{O(max)}$, $I_L = 1.0 \times I_{p(max)}$				IL = 1.0 X Ip	o(max)	35∞			
	Internal Driver Recovery Time		t _{on}							1000	ns µs	
	Max. Continuous Switching		f _(max)	Standard devices without HFS option					tion	1000	μο	
46	Frequency		I(IIIax)	@ V _{aux} = !	@ V _{aux} = 5.00 V Standard devices without in 3 option					tbd.		
NC.				Sw. shutdown	Sw. shutdown if f _(max) is exceeded Opt. HFS + sufficient cooling option				, ,			
100	Maximum Burst Frequency		f _{b(max)}	Use option HFB for >10 pulses within 20µs or less				• •		10	kHz	
	Maximum Number of Pulses / Burst		N _(max)	@ f _{b(max)} Standard						150 Use option HFB for >150	Pulses	
		, ,	- , ,	Note: Option HFB requires external buffer capacitors with a voltage rating of > 630VDC and a cpacitance of 100nF per additional pulse. Option I-HFB Option HFB				FB	>1000			
								rating of > 630		>10000		
	Coupling Capacitance		Cc	HV side against control side				320	pF			
	Control Voltage Range		V _{ctrl}		The V _{ctrl} has no impact on the output pulse shape.					4 5	VDC	
	Auxiliary Supply Voltage Range		Vaux		The +5 V supply is not required in the HFS mode.				5	VDC		
	Typical Auxiliary Supply Current		l _{aux}			0.01 x f _{(ma}	ax)	tbd.	ADC			
	Fault Circuit Outroit			Active current limitation above 1A. @ f _(max)						600	mADC	
	Fault Signal Output			Switch will be turn off, if f>f _(max) , V _{aux} <4.75V or T _{case} >75°C Fault condition is indicated by a logical "L"						H=4V, L=0.5V	VDC	
	Trigger Voltage Range		V _{TR}	Switching behaviour is not influenced by trigger quality				nuality		<10	VDC	
	Dimensions		LxWxH					quality		Please contact the	100	
9	Dimensions	EXTEN		Devices with option CF, non-isolated cooling fins					manufactured!	mm ³		
HOUSING				Devices with option DLC					manatarea.			
Ž	Weight	ı	Standard	Standard housing				Please contact the				
НС			Devices with option CF, non-isolated cooling fins						manufactured!	g		
		Devices with option DLC										
	Control Signal Input Pin 1 / Yellow. TTL compatible with Schmitt-Trigger characteristics. Control voltage 2-10								e 2-10 V (3	3-5 V recommended for low jitter).		
Logic GND / 5V Return Pin 2 / Black. The ground pin is internally connected with the safety earthing terminal (threaded insert) on bottom side.												
5V Auxiliary Supply Pin 3 / Red. The 5 V input is used for rep rates up to the specified max. frequency f _(max) . Higher rep rates require option HFS.												
710	Fault Signal Output Pin 4 / Orange. TTL output, short circuit proof. Indicating switch & driver over-heat, over-							, over-freq	uency, low auxiliary voltage. L = Fault.			
FUNCTIONS	Inhibit Signal Input Pin 5 / Green. TTL compatible, Schmitt-Trigger characteristics for the connection of exte							of external	safety circuits. L = Switch Inhibited.			
	LED Indicators		•	er good, switch OFF". YELLOW: "Control signal received, switch ON". RED: "Fault condition, switch OFF"								
	Temperature Protection									60 s @ 3xPd(max), ΔT =25K (50 to 75°C). Separate dr	river	
			n option DLC: 65°C, response time < 3 s @ 3xPd(max), ∆T=25K (40 t									
	HTS 240-1200 SCR Thyristo		Option LP Low Pass. Input filter for increased noise immunity. Option Coption S-TT Soft Transition Time. Slower switching speed for simplified EMC. Option C						• • • • • • • • • • • • • • • • • • • •			
		Opti	ů. i					Option CCF Option CF	Ceramic Flange Housing. P _{d(max)} can be increased by the factor 3 to Copper Cooling Fins. P _{d(max)} can be increased by the factor 3 to 10.			
GT!			O-4!						JUNUII LE			
RINGTI					• •		uxiliary supply input		Option GCF			
DERINGTI			Opti	on HFS Hi on UFTR UI	gh Frequency Swi tra Fast Thermotri	tching (two au gger. Respon	uxiliary supply input se time for shut dov	s V1 & V2) vn < 5s.	Option GCF Option ILC	Grounded Cooling Flange (copper). P _{d(max)} can be increased by the factor 3 Indirect Liquid Cooling (for water). P _{d(max)} can be increased by the factor 3 to	3 to 15.	
ORDERINGTI			Opti	on HFS Hi on UFTR UI on UFTS UI	gh Frequency Swi tra Fast Thermotri tra Fast Thermose	tching (two au gger. Respon ensor. Respor	uxiliary supply input	s V1 & V2) vn < 5s. 10k / ± 1%	Option GCF Option ILC Option DLC	Grounded Cooling Flange (copper). P _{d(max)} can be increased by the factor 3 Indirect Liquid Cooling (for water). P _{d(max)} can be increased by the factor 3 to Direct Liquid Cooling (for FPE/PFC). P _{d(max)} can be increased by the factor 1	3 to 15.	